

## isc N-Channel MOSFET Transistor

## IXTA3N60P

## • FEATURES

- Static drain-source on-resistance:  
 $R_{DS(on)} \leq 2.9\Omega @ V_{GS}=10V$
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## • APPLICATION

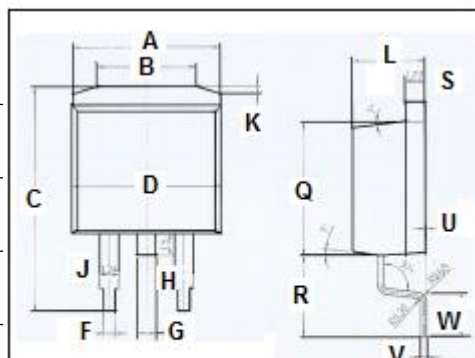
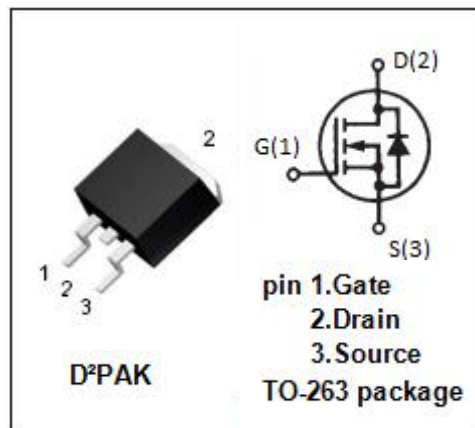
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

• ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ C$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DS}$	Drain-Source Voltage	600	V
$V_{GS}$	Gate-Source Voltage	$\pm 30$	V
$I_D$	Drain Current-Continuous	3	A
$I_{DM}$	Drain Current-Single Pulsed	6	A
$P_D$	Total Dissipation @ $T_c=25^\circ C$	70	W
$T_j$	Operating Junction Temperature	-55~150	$^\circ C$
$T_{stg}$	Storage Temperature	-55~150	$^\circ C$

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Junction-to-case thermal resistance	1.79	$^\circ C/W$



DIM	mm	
	MIN	MAX
A	10	
B	6.6	6.8
C	15.23	15.25
D	10.15	10.17
F	0.76	0.78
G	1.26	1.28
H	1.4	1.6
J	1.33	1.35
K	0.4	0.6
L	4.6	4.8
Q	8.69	8.71
R	5.28	5.30
S	1.26	1.28
U	0.0	0.2
V	0.37	0.39
W	2.80	2.82

**isc N-Channel MOSFET Transistor****IXTA3N60P****ELECTRICAL CHARACTERISTICS** $T_c=25^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V$ ; $I_D = 250\ \mu A$	600		V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$ ; $I_D = 50\ \mu A$	3.0	5.5	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V$ ; $I_D = 1.5A$		2.9	$\Omega$
$I_{GSS}$	Gate-Source Leakage Current	$V_{GS} = \pm 30V$ ; $V_{DS}=0V$		$\pm 100$	nA
$I_{DSS}$	Drain-Source Leakage Current	$V_{DS} = V_{DSS}$ ; $V_{GS} = 0V$		5	$\mu A$
		$V_{DS} = V_{DSS}$ ; $V_{GS} = 0V$ ; $T_J = 125^{\circ}\text{C}$		50	
$V_{SD}$	Diode forward voltage	$I_F = 3A$ ; $V_{GS} = 0V$		1.5	V

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